NDP23B0QB

15A,30V High Efficiency Synchronous Step-Down DC/DC Converter

Description

NDP23B0QB is a high efficiency, monolithic synchronous step-down DC/DC converter utilizing a Jitter frequency, average current mode control architecture. Capable of delivering up to 15A continuous load with excellent line and load regulation. The device operates from an input voltage range of 7V to 30V and provides an adjustable output voltage from 2V to 25V.

The NDP23B0QB features short circuit and thermal protection circuits to increase system reliability. The internal soft-start avoids input inrush current during startup.

The NDP23B0QB require a minimum number of external components. and a wide array of protection features to enhance reliability.

Features

- Wide VIN Range : 7V to 30V
- 15A Continuous Output Current
- Up to 96% Efficiency
- Adjustable Output Voltages
- +/-2% Output Voltage Accuracy
- Integrated 5mΩ High Side Switch
- Integrated 3mΩ Low Side Switch
- Programable Frequency(130KHz~330KHz)
- Burst Mode Operation at Light Load
- Internal loop Compensation
- Internal Soft Start
- Thermally Enhanced QFN5*5 Package

Applications

- Rechargeable Portable Devices
- Networking Systems
- Distributed Power Systems

Typical Application
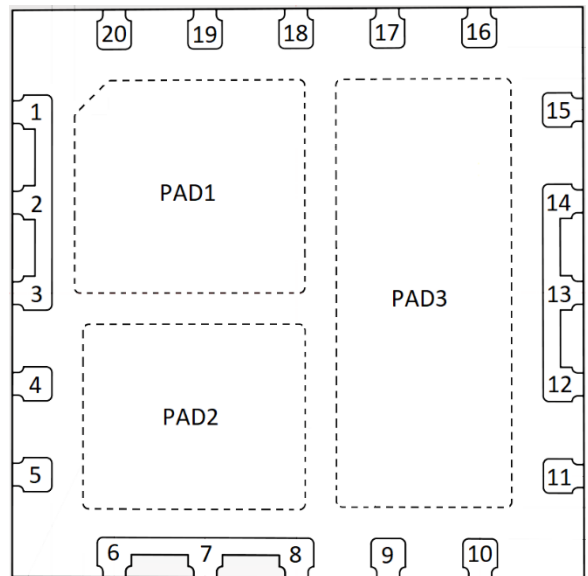

NDP23B0QB
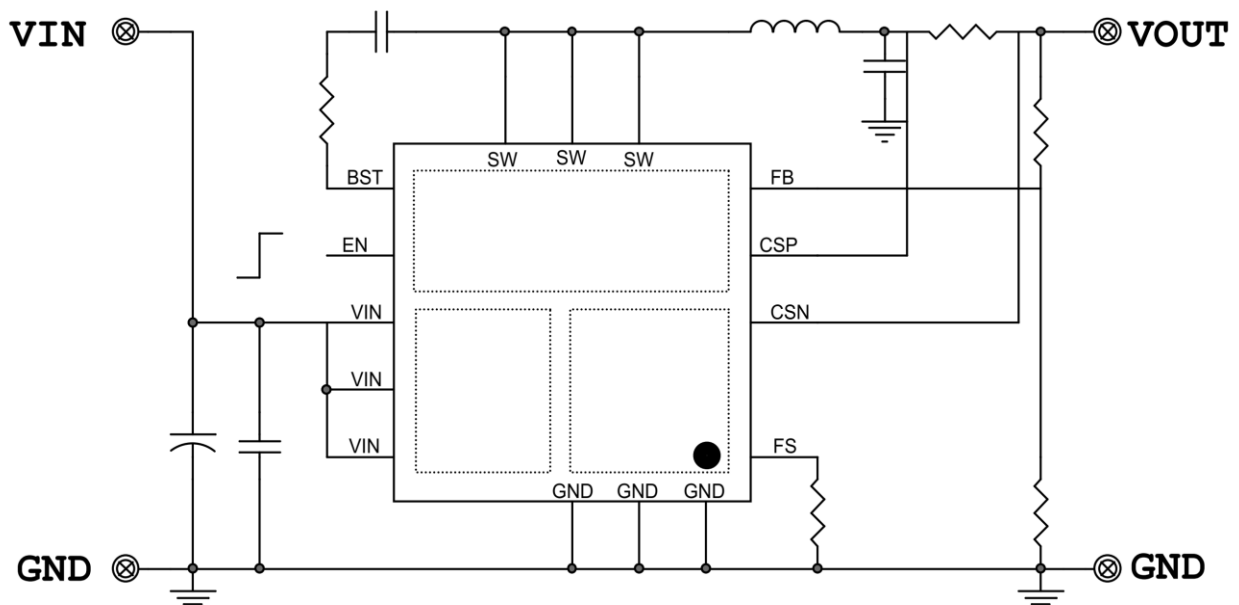
Absolute Maximum Ratings (at TA = 25°C)

Characteristics	Symbol	Rating	Unit
VIN to GND		-0.3 to 34	V
SW to GND		-0.3 to VIN+0.3	V
BST to GND		-0.3 to VIN+7	
FB, FS to GND		-0.3 to 6	V
CSP, CSN1, CSN2 to GND		-0.3 to 25	V
Junction to Ambient Thermal Resistance		105	°C/W
Operating Junction Temperature		-40 to 150	°C
Storage Junction Temperature		-55 to 150	°C
Thermal Resistance from Junction to case	θ_{JC}	15	°C/W
Thermal Resistance from Junction to ambient	θ_{JA}	40	°C/W

Pin Function And Descriptions

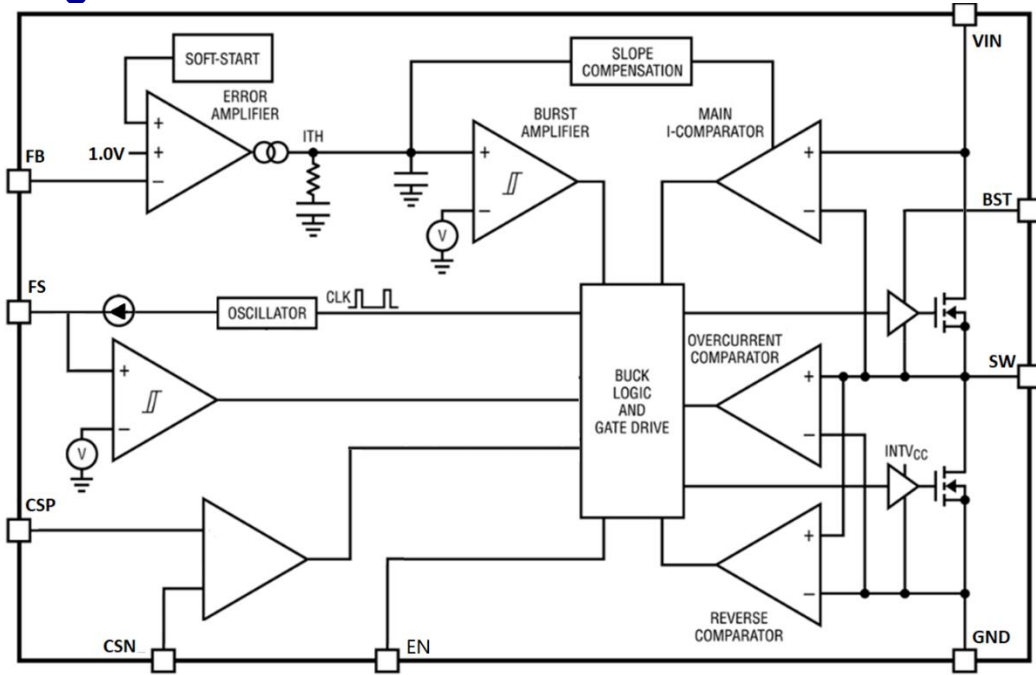| PIN	NAME	Description
1,2,3, PAD1	GND	Ground
4,5	NC	Not Connected
6,7,8,PAD2	VIN	Power Input Positive Pole
9	NC	Not Connected
10	BST	Boot Strap
11	NC	Not Connected
12,13,14,PAD3	SW	Switching, Connected With a Inductor
15	NC	Not Connected
16	VFB	Feedback Of Output Voltage
17	CSP	Positive side of Current Sense resistor if not used please left floating
18	CSN	Negative Positive side of Current Sense resistor if not used please left floating
19	EN	Enable internal pull up
20	FS	Connect a Resistor to GND for Frequency Config

Order information

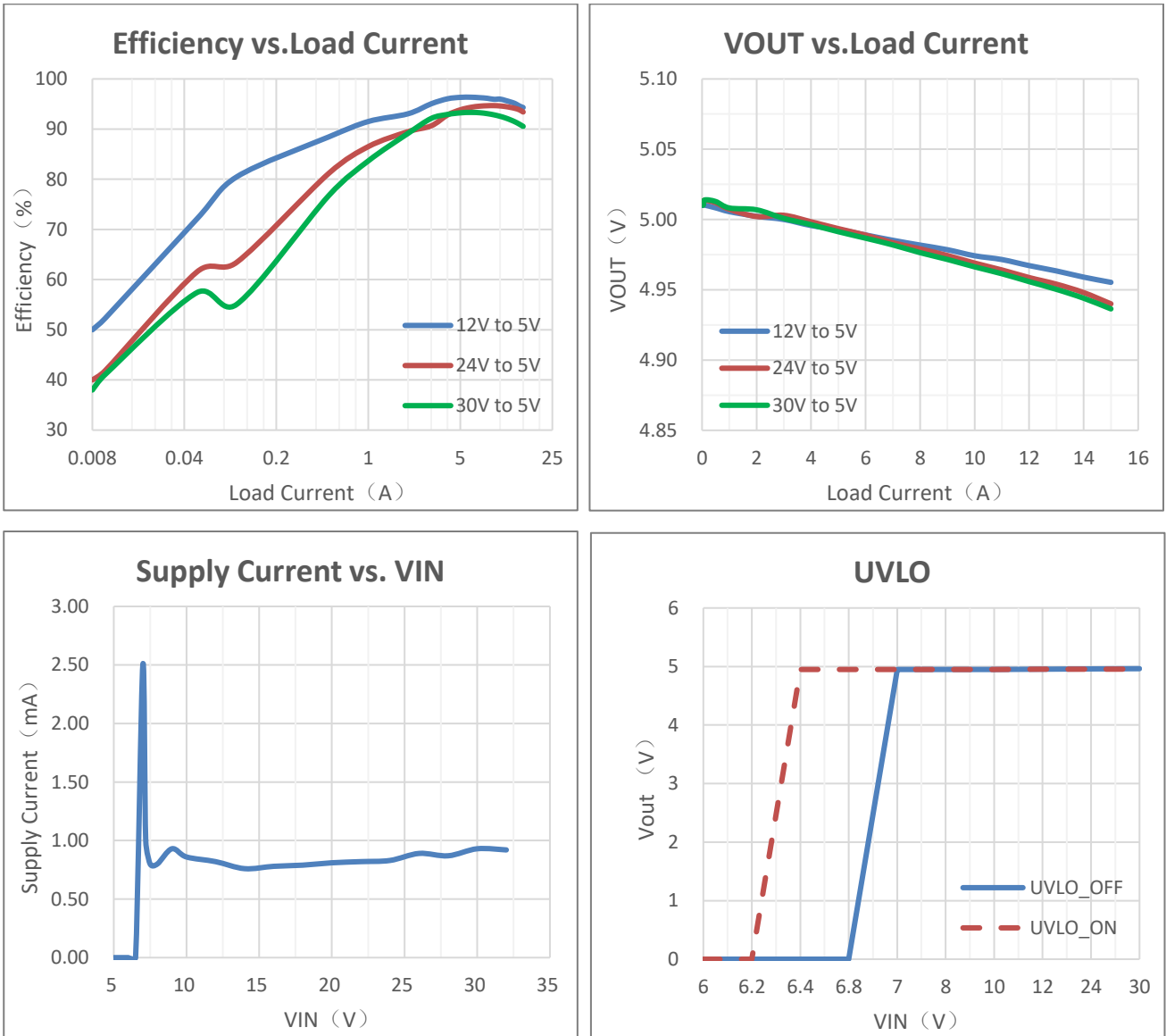| Order Information	Top Marking
NDP23B0 Q B Pin NO. B:20 Package Q: QFN5*5 Product Number	NDP23B0QB B-DYWWX O Y: Year (1=2021,2=2022,…) WW: Weekly (01-53) D/X : Internal ID Code B: Sub BIN(A=BIN A, B=BIN B)

（Note：MSL3）

Electrical Characteristics

TJ = 25°C. VIN = 12V, unless otherwise noted

Characteristics	Symbol	Conditions	Min	Typ	Max	Units
Input Voltage	VIN		7	-	30	V
UVLO Voltage	V_{UVLO}			6.8	7	V
UVLO Hysteresis				0.8		V
Quiescent Current	I_{CCQ}	V_{FB} = 1.2V, no switch	-	1300	-	uA
Standby Current	I_{SB}	No Load	-	1.7	2.2	mA
FB Reference Voltage	V_{FB}		0.980	1	1.020	V
Current Sense AMP	$V_{CS-BIN A}$	CSP-CSN	28	30	32	mV
	$V_{CS-BIN B}$		24	26	28	mV
Switching Frequency	F_{SW}	FS Floating		130		KHz
		Connect 56K resister		330		KHz
EN_H			1			V
EN_L					0.3	V
Maximum Duty Cycle				98	-	%
Minimum On-Time			-	250	-	ns
Current Limit	I_{LIM}		20			A
Hicup Interval	Thicup			400		mS
Soft start Time	Tss			1.2		mS
RDS$_{ON}$ Of Power MOS	High side	Temp=25℃		5		mΩ
	Low side	Temp=25℃		3		mΩ
Thermal Regulation	T_{TR}			145		°C
Thermal shutdown Temp	T_{SD}		-	160	-	°C
Thermal Shutdown Hysteresis	T_{SH}		-	30	-	°C

Block Diagram

Typical Performance Characteristics (TJ = 25°C, unless otherwise noted)

Efficiency vs.Load Current

VOUT vs.Load Current

Supply Current vs. VIN

UVLO

(CH1=Vin, CH2=SW, CH3=Vout, CH4=Isw）

Power On
Vin=12V, Vout=5.05V, Iout=15A

Power On
Vin=24V, Vout=5.05V, Iout=15A

Power Off Vin=12V, Vout=5.05V, Iout=15A	Power Off Vin=24V, Vout=5.05V, Iout=15A
Output Vin=12V, Vout=5.05V, Iout=15A	**Output** Vin=24V, Vout=5.05V, Iout=15A
Short Circuit Vin=12V, Cycle =364ms	**Short Circuit** Vin=12V, Freq=129kHz
Short Circuit Vin=24V, Cycle =326ms	**Short Circuit** Vin=12V, Freq=125kHz
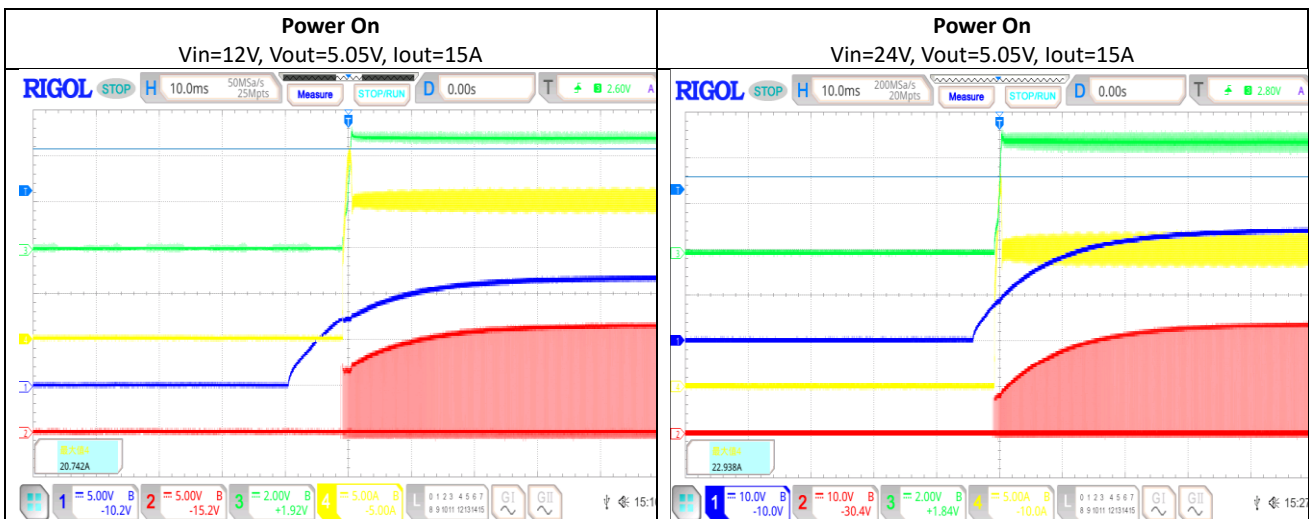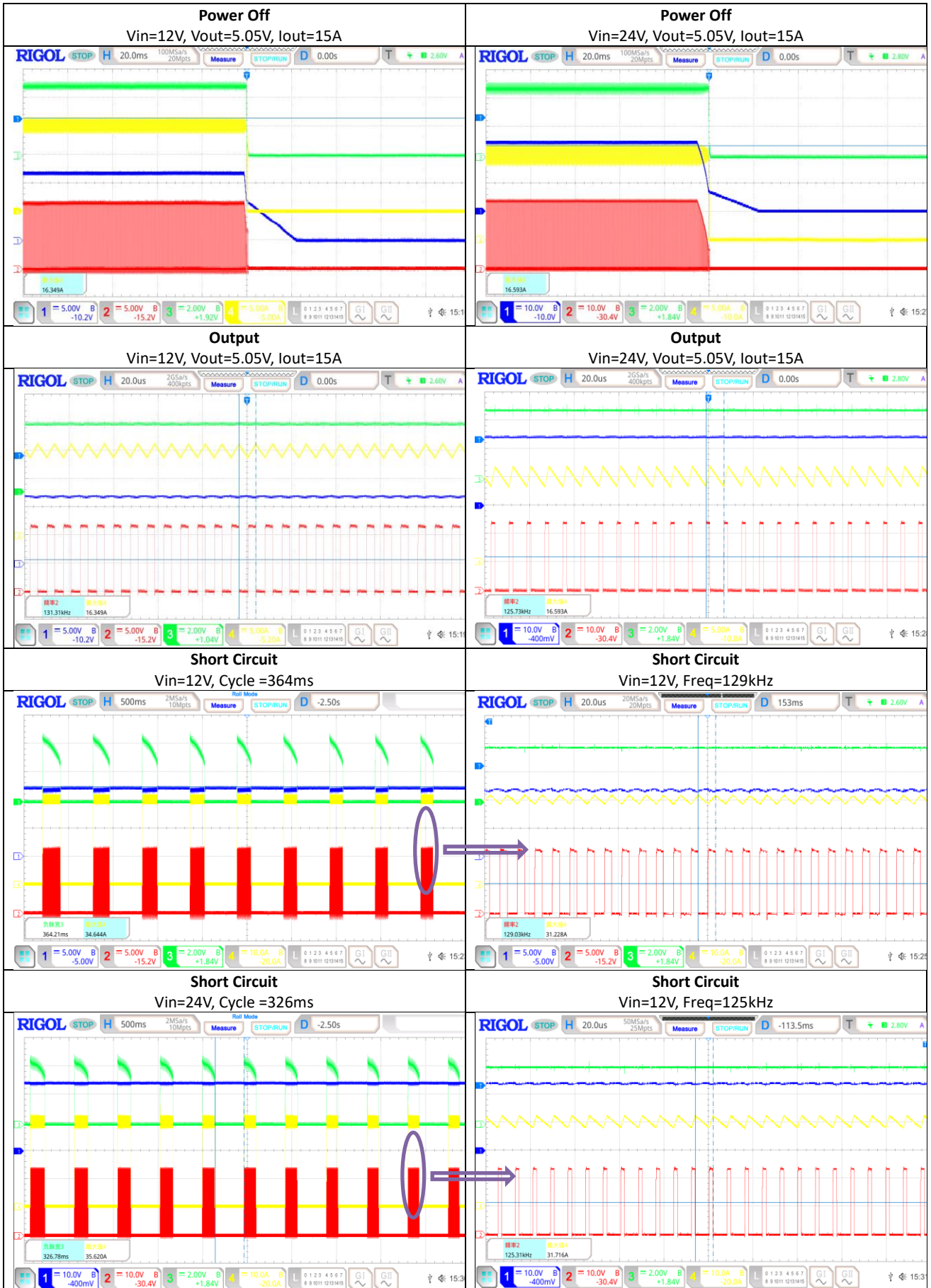
Operation

The NDP23B0QB is a high efficiency, monolithic, synchronous step-down DC/DC converter utilizing a Jitter frequency, average current mode control architecture. Average current mode control enables fast and precise control of the output current. It operates through a wide VIN range and regulates with low quiescent current. An error amplifier compares the output voltage with a internal reference voltage of 1.0V and adjusts the peak inductor current accordingly. overvoltage and undervoltage comparators will turn off the regulator.

Main Control Loop

During normal operation, the internal top power switch (N-channel MOSFET) is turned on at the beginning of each clock cycle, causing the inductor current to increase. The sensed inductor current is then delivered to the average current amplifier, whose output is compared with a saw-tooth ramp. When the voltage exceeds the vduty voltage, the PWM comparator trips and turns off the top power MOSFET. After the top power MOSFET turns off, the synchronous power switch (N-channel MOSFET) turns on, causing the inductor current to decrease. The bottom switch stays on until the beginning of the next clock cycle, unless the reverse current limit is reached and the reverse current comparator trips. In closed-loop operation, the average current amplifier creates an average current loop that forces the average sensed current signal to be equal to the internal ITH voltage. Note that the DC gain and compensation of this average current loop is automatically adjusted to maintain an optimum current-loop response. The error amplifier adjusts the ITH voltage by comparing the divided-down output voltage (VFB) with a 1.0V reference voltage. If the load current changes, the error amplifier adjusts the average inductor current as needed to keep the output voltage in regulation.

Low Current operation

The discontinuous-conduction modes (DCMs) are available to control the operation of the NDP23B0QB at low currents. Burst Mode operation automatically switch from continuous operation to the Burst Mode operation when the load current is low

Frequency Selection and Shutdown

The switching frequency of the NDP23B0QB can be programmed through an external resistor between 85kHz and 330 kHz，Floating this pin set the switching frequency to 130K, an external resistor can set the frequency up to 330KHz。the switching frequency is set using the FS pins as shown in Table 1:

FS Resistor(KΩ)	Frequency(KHz)
Floating	130
1000	140
750	147
510	161
300	170
200	190
150	200
120	230
100	250
75	280
62	300
56	330

Table 1

Output Voltage Regulation

The precision resistor connected between CSP and CSN is used to detect the output current. When the voltage across sampling resistor

exceeds VCS, the output voltage will decrease as the increase of the voltage on the sampling resistor, and the maximum reduction range of the output voltage is 5%

Applications Information

Input Capacitor (CIN) Selection

The input capacitance CIN is needed to filter the square wave current at the drain of the top power MOSFET. To prevent large voltage transients from occurring, a low ESR input capacitor sized for the maximum RMS current should be used. The maximum RMS current is given by:

$$I_{RMS} \cong I_{OUT(MAX)} \frac{V_{OUT}}{V_{IN}} \sqrt{\frac{V_{IN}}{V_{OUT}} - 1}$$

This formula has a maximum at VIN = 2VOUT, where: IRMS $\cong$ IOUT/2

This simple worst-case condition is commonly used for design because even significant deviations do not offer much relief. Note that ripple current ratings from capacitor manufacturers are often based on only 2000 hours of life which makes it advisable to further derate the capacitor, or choose a capacitor rated at a higher temperature than required. Several capacitors may also be paralleled to meet size or height requirements in the design. For low input voltage applications, sufficient bulk input capacitance is needed to minimize transient effects during output load changes.

Output Capacitor (COUT) Selection

The selection of COUT is determined by the effective series resistance (ESR) that is required to minimize voltage ripple and load step transients as well as the amount of bulk capacitance that is necessary to ensure that the control loop is stable. Loop stability can be checked by viewing the load transient response. The output ripple, $\triangle$VOUT, is determined by:

$$\Delta V_{OUT} < \Delta I_L \left(\frac{1}{8 \bullet f \bullet C_{OUT}} + ESR \right)$$

The output ripple is highest at maximum input voltage since $\triangle$IL increases with input voltage. Multiple capacitors placed in parallel may be needed to meet the ESR and RMS current handling requirements. Dry tantalum, special polymer, aluminum electrolytic, and ceramic capacitors are all available in surface mount packages. Special polymer capacitors are very low ESR but have lower capacitance density than other types. Tantalum capacitors have the highest capacitance density but it is important to only use types that have been surge tested for use in switching power supplies. Aluminum electrolytic capacitors have significantly higher ESR, but can be used in cost-sensitive applications provided that consideration is given to ripple current ratings and long-term reliability. Ceramic capacitors have excellent low ESR characteristics and small footprints.

Inductor Selection

Given the desired input and output voltages, the inductor value and operating frequency determine the ripple current:

$$\Delta I_L = \frac{V_{OUT}}{F * L} \left(1 - \frac{V_{OUT}}{V_{IN(MAX)}} \right)$$

Lower ripple current reduces power losses in the inductor, ESR losses in the output capacitors and output voltage ripple. Highest efficiency operation is obtained at low frequency with small ripple current. However, achieving this requires a large inductor. There is a trade-off between component size, efficiency and operating frequency. A reasonable starting point is to

choose a ripple current that is about 40% of IOUT(MAX). To guarantee that ripple current does not exceed a specified maximum, the inductance should be chosen according to:

$$L = \frac{V_{OUT}}{F * \Delta I_{L(MAX)}} \left(1 - \frac{V_{OUT}}{V_{IN(MAX)}}\right)$$

Once the value for L is known, the type of inductor must be selected. Actual core loss is independent of core size for a fixed inductor value, but is very dependent on the inductance selected. As the inductance or frequency increases, core losses decrease. Unfortunately, increased inductance requires more turns of wire and therefore copper losses will increase. Copper losses also increase as frequency increases Ferrite designs have very low core losses and are preferred at high switching frequencies, so design goals can concentrate on copper loss and preventing saturation. Ferrite core material saturates "hard", which means that inductance collapses abruptly when the peak design current is exceeded. This results in an abrupt increase in inductor ripple current and consequent output voltage ripple. Do not allow the core to saturate!

Different core materials and shapes will change the size/current and price/current relationship of an inductor. Toroid or shielded pot cores in ferrite or permalloy materials are small and don't radiate much energy, but generally cost more than powdered iron core inductors with similar characteristics. The choice of which style inductor to use mainly depends on the price versus size requirements and any radiated field/EMI requirements. New designs for surface mount inductors are available from Coilcraft, Toko, Vishay, NEC/Tokin, TDK and Würth Electronik.

Efficiency Considerations

The percent efficiency of a switching regulator is equal to the output power divided by the input power times 100%. It is often useful to analyze individual losses to determine what is limiting the efficiency and which change would produce the most improvement. Percent efficiency can be expressed as: % Efficiency = 100% – (Loss1 + Loss2 + …) where Loss1, Loss2, etc. are the individual losses as a percentage of input power. Although all dissipative elements in the circuit produce losses, three main sources usually account for most of the losses in NDP23B0QB circuits: 1) I2R losses, 2) switching and biasing losses, 3) other losses.

Thermal Conditions

In a majority of applications, the NDP23B0QB does not dissipate much heat due to its high efficiency and low thermal resistance. However, in applications where the NDP23B0QB is running at high ambient temperature, high VIN, and maximum output current load, the heat dissipated may exceed the maximum junction temperature of the part. If the junction temperature reaches approximately 150°C, both power switches will be turned off until the temperature drops about 30°C cooler To avoid the NDP23B0QB from exceeding the maximum junction temperature, the user will need to do some thermal analysis. The goal of the thermal analysis is to determine whether the power dissipated exceeds the maximum junction temperature of the part. If the application calls for a higher ambient temperature and/or higher switching frequency, care should be taken to reduce the temperature rise of the part by using a heat sink or forced air flow.
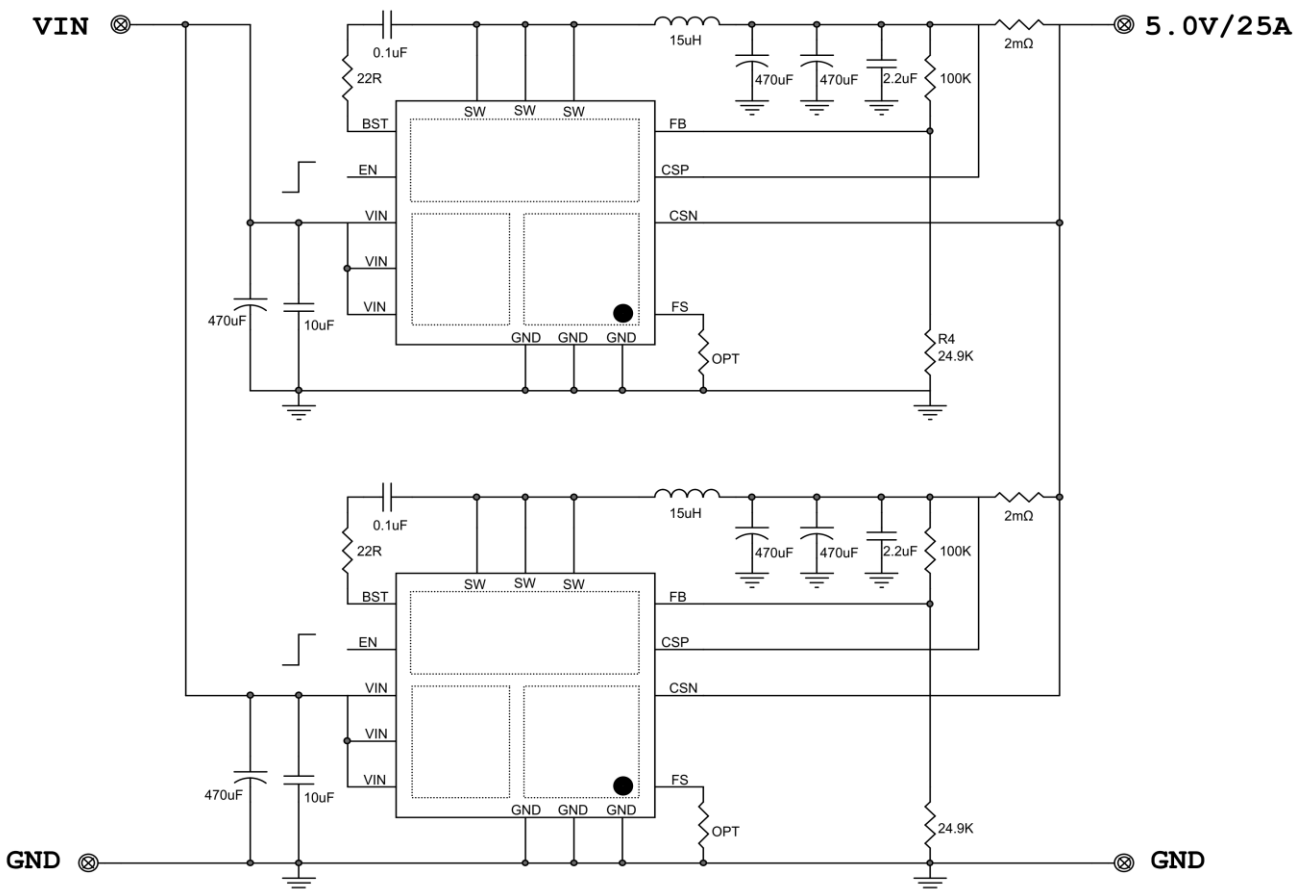
NDP23B0QB

EMI/EMC

In order to solve EMI electromagnetic interference, SW pin should add a circuit of RC filter, a 20Ω resistor and a 1nF capacitor, BST

pin reserved 20Ω string 100nF.If the application version enough volume,can be reserved at input end type Π circuit.

Typical application
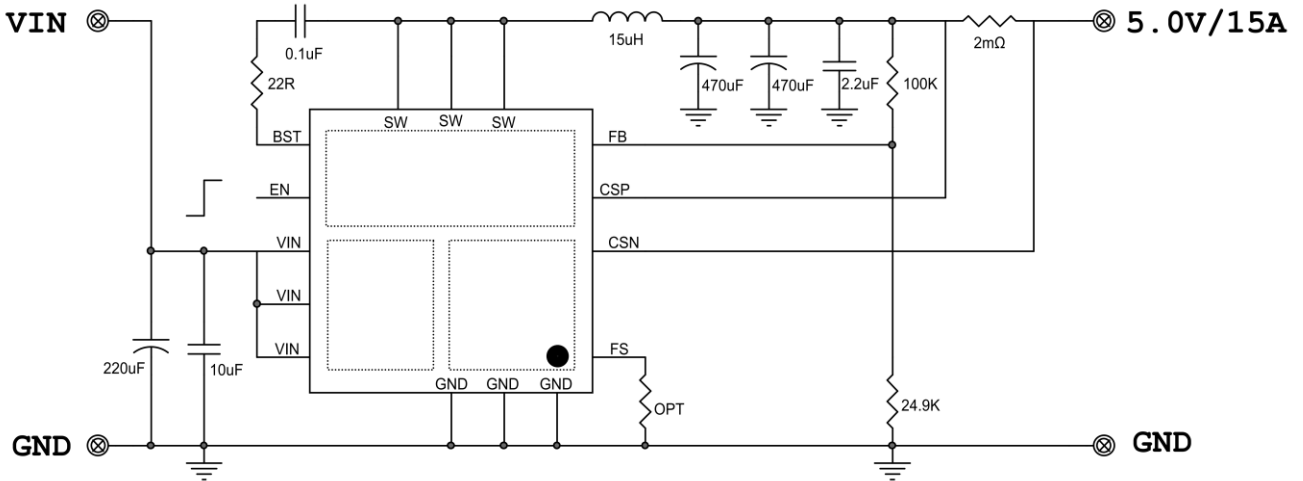
Simple Bench Power Supply
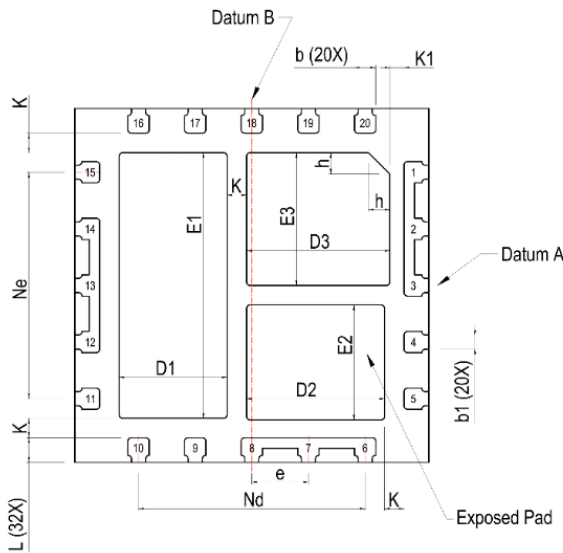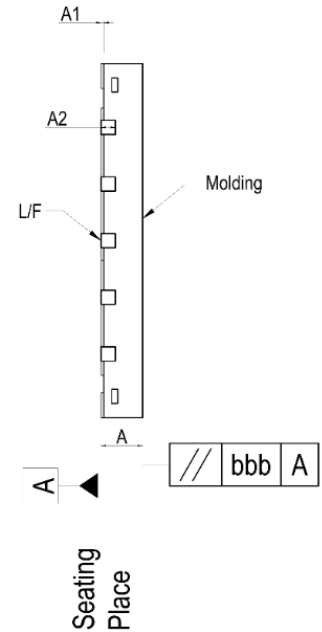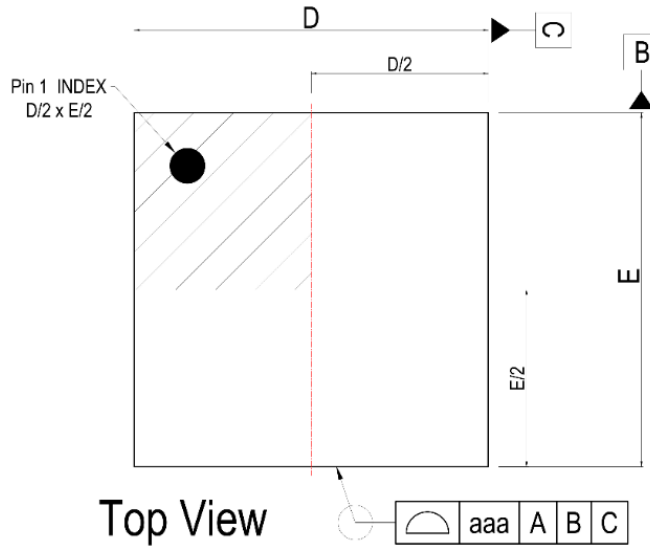

Dual Tracking Bench Power Supply

NDP23B0QB

Package Description

QFN5*5-20 Outline Package

Top View

Side View

Bottom View

Dimensional References					Unit: mm		
Ref	MIN	NOR	MAX	Ref	MIN	NOR	MAX
A	0.7	0.75	0.8	D1	1.475	1.525	1.575
A1	0.00	-	0.05	E1	3.700	3.750	3.800
D	4.90	5.00	5.10	D2	1.900	1.950	2.000
E	4.90	5.00	5.10	E2	1.575	1.625	1.675
A2		0.203		D3	1.975	2.025	2.075
Ne		3.20		E3	1.825	1.875	1.925
Nd		3.20		b	0.250	0.300	0.350
b1		0.20		L	0.300	0.350	0.400
e		0.80		h	0.250	0.300	0.350
aaa		0.05		k	0.225	0.275	0.325
bbb		0.10		k1	0.150	0.200	0.250